

PRODUKTINFORMATION

Vi reserverar oss mot fel samt förbehåller oss rätten till ändringar utan föregående meddelande

ELFA artikelnr 75-512-37 LCD 20x2 TN

SPECIFICATIONS

Description <u>LCM</u>

Model name <u>GTC-20021-YR6N0C</u>

HEBEI GEM-TECH ELECTRONICS CO., LTD.

Contents

- **1.BASIC SPECIFICATION**
- 2. ABSOLUTE MAXIMUM RATINGS
- 3. ELECTRICAL & OPTICAL CHARACTERISTICS
- 4. TERMINAL CHARACTERISTICS
- 5. FUNCTION DESCRIPTION& INSTRUCTION SET
- 6. CHARACTER FONT TABLE
- 7. DIMENSIONAL OUTLINE
- 8. QUALITY SPECIFICATION
- 9. RELIABILITY
- 10. HANDLING PRECAUTION
- 11. PRECAUTION FOR USE

HEBEI GEM-TECH ELECTRONICS CO., LTD. 1 P/N: GTC-20021YR6N0C

1. BASIC SPECIFICATION

1-1 DISPLAY SPECIFICATIONS

. DISPLAY MODE : STN-TRANSFLECTIVE-POSITIVE-YELLOW-GREEN

. DISPLAY FORMAT : 20 CHARACTERS X 2 LINES

. INPUT DATA : 8-BITS PARALLEL DATA INPUT FROM A MPU

. MULTIPLEXING : 1/16 DUTY . VIEWING DIRECTION : 6 O'CLOCK

. DRIVED IC : KS0066U(1Chip) + KS0065B (2 Chips)

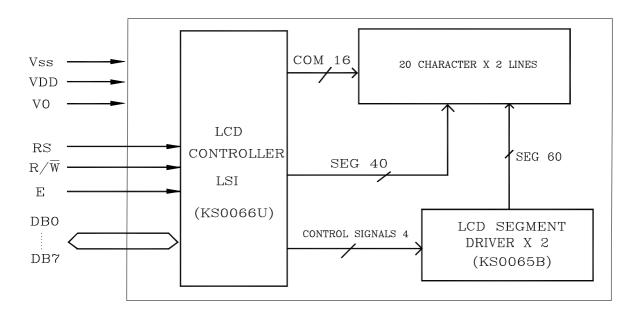
. BEZEL : 0.6T

. OTHERS :

1-2. MECHANICAL SPECIFICATION

ITEM	SPECIFICATIONS	UNIT	REMARK
DIMENSIONAL OUTLINE	116.0(W)×37.0(H)×9.5MAX.(T)		*REFERENCE
VIEW AREA	83.0(W)×18.6(H)	mm	DIMENSIONAL
EFFECTIVE V/AREA	75.4(W)×11.5(H)		OUTLINE
NUMBER OF CHARACTERS	20 CHARACTERSX2LINES		
DOT PITCH	0.65(W)×0.70(H)	mm	
DOT SIZE	0.60(W)×0.65(H)	mm	

1-3 BLOCK DIAGRAM

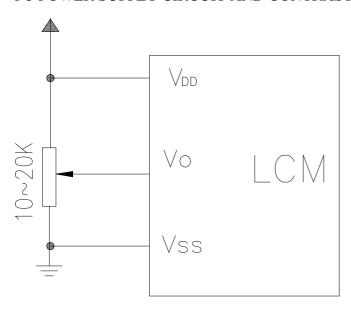


HEBEI GEM-TECH ELECTRONICS CO., LTD. 2 P/N: GTC-20021YR6N0C

1-4 TERMINAL FUNCTIONS

PIN NO	SYMBOL	LEVEL	DESCRIPTION
1	Vss	1	GROUND
2	V_{DD}	-	POWER SUPPLY FOR LOGIC
3	Vo	-	POWER SUPPLY FOR LCD
4	RS	H/L	REGISTER SELECTION
5	R/W	H/L	READ/WRITE
6	E	H, H/L	ENABLE SIGNAL
7	DB0	H/L	DATA BIT0
8	DB1	H/L	DATA BIT1
9	DB2	H/L	DATA BIT2
10	DB3	H/L	DATA BIT3
11	DB4	H/L	DATA BIT4
12	DB5	H/L	DATA BIT5
13	DB6	H/L	DATA BIT6
14	DB7	H/L	DATA BIT7

1-5 POWER SUPPLY CIRCUIT AND CONTRAST ADJUST



2. ABSOLUTE MAXIMUM RATINGS (Ta=25 °C, Vss=0V)

PARAMETER	SYMBOL	RATINGS			UNITS
		MIN.	TYP.	MAX.	
POWER SUPPLY FOR LOGIC	V _{DD} -V _{SS}	0	1	7.0	V
POWER SUPPLY FOR LCD DRIVER	V _{DD} -V0	0	ı	12.0	V
INPUT VOLTAGE	Vin	Vss	ı	V_{DD}	V
OPERATING TEMPERATURE	Topr	0	i	50	°C
STORAGE TEMPERATURE	Tstg	-20	1	70	°C

HEBEI GEM-TECH ELECTRONICS CO., LTD. 3

3.ELECTRICAL & OPTICAL CHARACTERISTICS

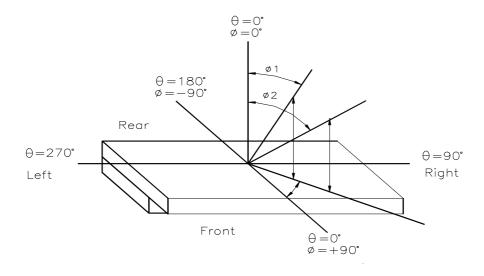
3-1 ELECTRICAL CHARACTERISTICS (Ta=25°C)

ITEM	SYMBOL	CONDITION	MIN	TYPE	MAX.	UNIT
LOGIC CIRCUIT						
POWER SUPPLY	V _{DD} -V _{SS}		4.5	5.0	5.5	V
VOLTAGE						
INPUT VOLTAGE	Vih		2.2	_	V_{DD}	V
INPUT VOLTAGE	VIL		Vss		0.6	V
LOGIC CIRCUIT						
POWER SUPPLY	Idd	$V_{DD}-V_{SS}=5.0V$		2.0	3.0	Ma
CURRENT						
RECOMMENDED	V _{DD} -V0					
LCD DRIVING	ф=0	Ta=25 °C		5.0		V
VOLTAGE	$\theta = 0$					
FRAME FREQUNCY	fFLM	-	-	128		Hz

3-2. ELECTRO—OPTICAL CHARACTERISTICS(Ta=25 °C VDD=5.0±0.25V)

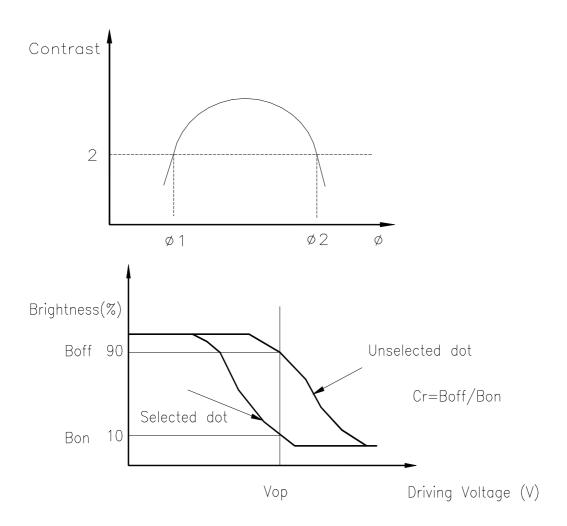
ITEM	SYMBOL	CONDITION	MIN	TYPE	MAX	UNIT
VIEW ANGLE	?ф	θ=0°(Cr≥2)	35	40		Deg
		0°<φ1, φ2<90°				
CONTRAST	Cr	φ=15°,θ=0°	3	5		_
		6 O'CLOCK				
RESPONSE TIME	tr(rise)	6 O'CLOCK	_	250	350	ms
	tf(fall)	φ=15°,θ=0°	_	250	350	ms

NOTE1: Definition of Viewing Angle θ,ϕ

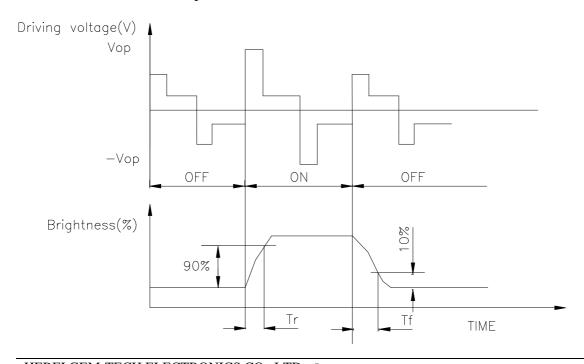


NOTE2: Definition of viewing Angle Range: $?\phi = |\phi 2 - \phi 1|$

NOTE3: Definition of Contrast



NOTE4: Definition of Response Time



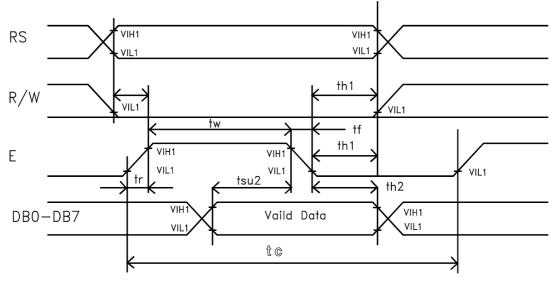
4. TERMINAL CHARACTERISTICS

4-1. TIMING OF WRITE/READ OPERATION(VDD=5.0V ±10%,Ta=0 TO 50 °C)

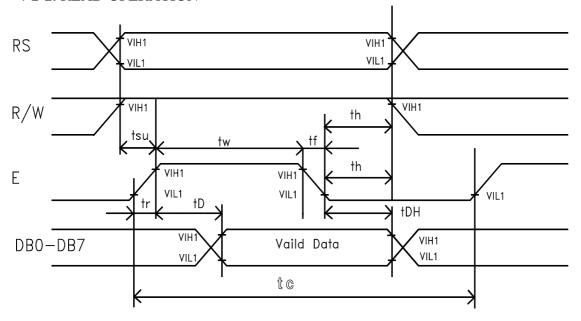
ITEM	SYMBOL	WRITE		READ		UNIT
		MIN.	MAX.	MIN.	MAX.	
ENABLE CYCLE TIME	tc	500	-	500	-	
ENABLE PULSE WIDTH	tw	220	-	220	-	
ENABLE RISE/FALL TIME	tr, tf	-	25	ı	25	ns
RS, R/W SET UP TIME	tsu1/tsu	40	-	40	-	
RS, R/W HOLD TIME	th1/th	10	-	10	-	
DATA SET-UP DELAY TIME	tsu2/tD	60	-	60	120	
DATA HOLD/HOLD TIME	th2/tDH	10	-	20	-	

4-2. INTERFACE TIMING CHART

4-2-1. WRITE OPERATION



4-2-2. READ OPERATION



5. FUNCTION DESCRIPTION& INSTRUCTION SET

5-1. FUNCTION DESCRIPTION (KS0066U)

System Interface

This chip has both kinds of interface type with MPU: 4-bit bus and 8-bit bus.

4-bit bus and 8-bit bus are selected by the DL bit in the instruction register.

During read or write operation, two 8-bits registers are used.

One is the data register (DR), and the other is the instruction register (IR).

The data register (DR) is used as a temporary data storage place for being written into or read from DDRAM/CGRAM. The target RAM is selected by RAM address setting instruction.

Each internal operation, reading from or writing into RAM, is done automatically.

Thus, after MPU read DR data, the data in the next DDRAM/CGRAM address is transferred into DR automatically. Also, after MPU writes data to DR, the data in DR is transferred into DDRAM/CGRAM automatically.

The Instruction register(IR) is used only to store instruction codes transferred from MPU. MPU cannot use it to read instruction data.

To select a register, you can use RS input pin in 4-bit/8-bit bus mode.

RS	R/W	Operation
L	L	Instruction Write operation (MPU write Instruction code into IR)
L	Н	Read Busy flag(DB7) and address counter (DB0 to DB6)
Н	L	Data Write operation (MPU write data into DR)
Н	Н	Data Read operation (MPU reads data from DR)

Busy Flag (BF)

BF= "High", indicates that the internal operation is being processed.

So during this time the next instruction cannot be accepted. BF can be read through DB7 port when RS = "Low" and R/W = "High" (Read Instruction Operation).

Before executing the next instruction, be sure that BF is not "High".

Address Counter (AC)

The address Counter (AC) stores DDRAM/CGRAM addresses, transferred from IR.

After writing into (reading from) DDRAM/CGRAM, AC is automatically increased (decreased) by 1.

When RS= "Low" and R/W= "High", AC can be read through ports DB0 to DB6.

Display Data RAM (DDRAM)

DDRAM stores display data of maximum 80X8 bits (80 characters).

DDRAM address is set in the address counter(AC) as a hexadecimal number (Refer to Fig-1.)

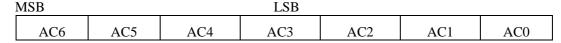


Figure 1. DDRAM Address

20 character * 2 line:

Line	Display position	1	2	3	4	••••	19	20
1	DDRAM	00H	01H	02H	03H	••••	12H	13H
	address							
Line	Display position	1	2	3	4	••••	19	20
2	DDRAM	40H	41H	42H	43H	•••••	52H	53H
	address							

CGROM (Character Generation ROM)

CGROM has a 5x8 dots 204 characters pattern and a 5x11 dots 32 characters pattern (Refer to the CGROM Character Code Table)

CGROM has 204 characters pattern of 5x8 dots, and 32 characters pattern of 5x11 dots.

CGRAM (Character Generation RAM)

CGRAM has up to 5x8 dots 8 characters.

By writing font data to CGRAM, user defined characters can be used.

Refer to follow table.

Relationship between Character Code (DDRAM) and Character Pattern (CGRAM)

Character Code	CGRAM Address	CGRAM Data	Pattern
(DDRAM data)			number
D7 D6 D5 D4 D3 D2 D1 D0	A5 A4 A3 A2 A1 A0	P7 P6 P5 P4 P3 P2 P1 P0	
0 0 0 0 x 0 0 0	0 0 0 0 0 0	x x x 0 1 1 1 0	pattern 1
	0 0 1	$1 \ 0 \ 0 \ 0 \ 1$	
	0 1 0	$1 \ 0 \ 0 \ 0 \ 1$	
	0 1 1	11111	
	1 0 0	$1 \ 0 \ 0 \ 0 \ 1$	
	1 0 1	$1 \ 0 \ 0 \ 0 \ 1$	
	1 1 0	$1 \ 0 \ 0 \ 0 \ 1$	
	1 1 1	0 0 0 0 0	
*	*	*	*
	*		
	*		
	*		
	*		
	*		
0 0 0 0 x 1 1 1	1 1 1 0 0 0	x x x 1 0 0 0 1	pattern 8
	0 0 1	$1 \ 0 \ 0 \ 0 \ 1$	
	0 1 0	$1 \ 0 \ 0 \ 0 \ 1$	
	0 1 1	11111	
	1 0 0	$1 \ 0 \ 0 \ 0 \ 1$	
	1 0 1	1 0 0 0 1	
	1 1 0	1 0 0 0 1	
	1 1 1	0 0 0 0 0	

5-2. INSTRUCTION SET

5-2-1. INSTRUCTION DESCRIPTION

Outline

To overcome the speed difference between the internal clock of KS0066U and the MPU clock, KS0066U performs internal operations by storing control information to IR or DR. The internal operation is determined according to the signal from MPU, composed of read/write and data bus. Instructions can be divided largely into four groups:

- 1) KS0066U function set instructions (set display methods, set data length, etc.)
- 2) Address set instructions to internal RAM.
- 3) Data transfer instructions with internal RAM.
- 4) Others.

The address of the internal RAM is automatically increased by 1.

Note: During internal operation, Busy Flag (DB7) is read "High".

Busy Flag check must be preceded by the next instruction.

When an MPU program with checking the Busy Flag (DB7) is made, it must be necessary 1/2 fosc for executing the next instruction by the falling edge of the "E" signal after the Busy

Flag (DB7) goes to "Low".

Contents

1) Clear Display

RS F	R/W DE	37 DB6	DB5	DB4 D	B3 DB2	2 DB1	DB0		
0	0	0	0	0	0	0	0	0	1

Clear all the display data by writing "20H" (space code) to all DDRAM address, and set DDRAM address to "00H" into AC(address counter).

Return cursor to the original status, namely, bring the cursor to the left edge on the first line of the display.

Make the entry mode increment (I/D="High").

2) Return Home

RS 1	R/W DI	37 DB6	DB5	DB4 D	B3 DB	2 DB1	DB0		
0	0	0	0	0	0	0	0	1	_

Return home is cursor return home instruction.

Set DDRAM address to "00H" into the address counter.

Return home to its original site and return display to its original status, if shifted.

Counters of DDRAM does not change.

3) Entry Mode Set

RS I	R/W DE	37 DB6	DB5	DB4 D	B3 DB	2 DB1	DB0		
0	0	0	0	0	0	0	1	I/D	SH

Set the moving direction of cursor and display.

I/D: Increment / decrement of DDRAM address (cursor or blink)

When I/D = "High", cursor/blink moves to right and DDRAM is increased by 1.

When I/D = ``Low'', cursor/blink moves to left and DDRAM is decreased by 1.

SH: shift of entire display

When DDRAM read (CGRAM read/write) operation or SH = "Low", shifting of entire display is not performed.

if SH = "High" and DDRAM write operation, shift of entire display is performed according to I/D value (I/D = "High": shift left, I/D = "Low": shift RIGHT).

HEBEI GEM-TECH ELECTRONICS CO., LTD. 9

^{*} CGRAM operates the same way as DDRAM, when reading from or writing to CGRAM.

4) Display ON/OFF Control

RS	R/W DI	37 DB6	DB5	DB4 D	B3 DB	2 DB1	DB0		
0	0	0	0	0	0	1	D	C	В

Control display /cursor/blink ON/OFF 1 bit register.

D: display on/off control bit

When D= "High", entire display is turned on.

When D = "Low", entire display is turned off, but display data remains in DDRAM,

C: cursor on/off cursor bit

When C = "High", cursor is turned on.

When C = "Low", cursor is disappeared in current display, but I/D register preserves its data.

B: cursor blink on/off control bit

When B = "High", cursor blink is on which performs alternately between all the "High" data and when B = "Low", blink is off.

5) Cursor or Display Shift

RS R	/W DB	7 DB6	DB5	DB4 DI	33 DB2	DB1	DB0	
0	0	0	0	0	0	S/C	R/L	

Shifting of right/left cursor position or display without writing or reading of display data.

This instruction is used to correct or search display data.

During 2-line mode display, cursor moves to the 2nd line after the 40th digit of the 1st line.

Note that display shift is performed simultaneously in all the lines.

When display data is shifted repeatedly, each line is shifted individually.

When display shift is performed, the contents of the address counter are not changed.

Shift patterns according to S/C and bits

S/C	R/L	Operation
0	0	Shift cursor to the left, AC is decreased by 1
0	1	Shift cursor to the right, AC is increased by 1
1	0	Shift all the display to the left, cursor moves according to the display
1	1	Shift all the display to the right, cursor moves according to the display

6) Function Set

RS	R/W DI	37 DB6	DB5	DB4	DB3 DB3	2 DB1	DB0		
0	0	0	0	1	DL	N	F	_	_

DL: interface data length control bit

When DL= "High", it means 8-bit bus mode with MPU.

When DL = "Low", it means 4-bit bus mode with MPU. Hence, DL is a signal to select 8-bit or 4-bit bus mode. When 4-bit bus mode, it needs to transfer 4-bit data twice.

N: display line number control mode is set.

When N= "Low", 1-line display mode is set.

When N = "High", 2-line display mode is set.

F: display font type control bit

When F= "Low", 5 x 8 dots format display mode is set.

When F= "High", 5 x 11 dots format display mode.

7) Set CGRAM Address

RS	R/W D	B7 DB6	5 DB5	DB4 I	DB3 DB	2 DB1	DB0		
0	0	0	1	AC5	AC4	AC3	AC2	AC1	AC0

Set CGRAM address to AC.

This instruction makes CGRAM data available from MPU.

8) Set DDRAM Address

RS .	R/W D	B7 DB6	5 DB5	DB4 D	DB3 DB	2 DB1	DB0		
0	0	1	AC6	AC5	AC4	AC3	AC2	AC1	AC0

Set DDRAM address to AC.

This instruction makes DDRAM data available from MPU.

When 1-line display mode (N=Low), DDRAM address is from "00H" to "27H".

In 2-line display mode (N=High), DDRAM address in the 1st line is from "00H" to "27H", and DDRAM address in the 2nd line is from "40H" to "67H".

9) Read Busy Flag & Address

RS	R/W I	DB7 DB6	5 DB5	DB4 D	DB3 DB	2 DB1	DB0		
0	1	BF	AC6	AC5	AC4	AC3	AC2	AC1	AC0

This instruction shows whether KS0066U is in internal operation or not.

If the resultant BF is "High", internal operation is in progress and should wait until BF is to be Low, which by then the next instruction can be performed. In this instruction you can also read the value of the address counter.

10) Write Data to RAM

K	5 K	/w DR	/ DR0	DR2 I	DB4 DI	35 DB_2	DRI	DR0		
	1	0	D7	D6	D5	D4	D3	D2	D1	D0

Write binary 8-bit data to DDRAM/CGRAM.

The selection of RAM from DDRAM, and CGRAM, is set by the previous address set instruction (DDRAM address set, CGRAM address set).

RAM set instruction can also determine the AC direction to RAM.

After write operation, the address is automatically increased/ decreased by 1, according to the entry mode.

11) Read Data from RAM

KS K	AM DR	/ DB6	DB2	DB4 DI	33 DB2	DBI	DR0		
1	1	D7	D6	D5	D4	D3	D2	D1	D0

Read binary 8-bit data from DDRAM/CGRAM.

The selection of RAM is set by the previous address set instruction if the address set instruction of RAM is not performed before this instruction, the data that has been read first is invalid, as the direction of AC is not yet determined. If RAM data is read several times without RAM address instructions set before read operation, the correct RAM data can be obtained from the second. But the first data would be incorrect, as there is no time margin to transfer RAM data.

In case of DDRAM read operation, cursor shift instruction plays the same role as DDRAM address set instruction, it also transfers RAM data to output data register.

After read operation, address counter is automatically increased/ decreased by 1 according to the entry mode.

HEBEI GEM-TECH ELECTRONICS CO., LTD. 11

After CGRAM read operation, display shift may not be executed correctly.

Note: In case of RAM write operation, AC is increased/decreased by 1 as in read operation.

At this time, AC indicates the next address position, but only the previous data can be read by the read instruction.

5-2-2. INSTRUCTION

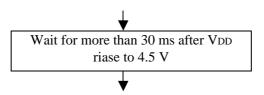
Instruction Instruction code					Description	Execution time						
	RS	R/	DB	DB	DB	DB	DB	DB	DB	DB		(fosc=270KHz)
		W	7	6	5	4	3	2	1	0		
Clear	0	0	0	0	0	0	0	0	0	1	Write 20H to DDRAM and set	1.53ms
Display											DDRAM address to 00H from	
											AC	
Return	0	0	0	0	0	0	0	0	1	-	Set DDRAM address to 00H	1.53ms
Home											From AC and return cursor to its	
											Original position if shifted.	
											The contents of DDRAM are not	
F . M .	_	_	_	0	0		0	1	I/D	CII	Changed.	20
Entry Mode	0	0	0	0	0	0	0	1	I/D	SH	Assign cursor moving direction And enable the shift of entire	39us
Set											display.	
Display ON/	0	0	0	0	0	0	1	D	С	В	Set display(D), cursor(C),	39us
OFF Control	0	U	U	0	U	U	1	ט	C	ь	and blinking of cursor(B) on/off	3948
Off Control											control bit.	
Cursor or	0	0	0	0	0	1	S/C	R/L	_	_	Set cursor moving and display	39us
Display											shift control bit, and the	
Shift											direction,	
											without changing of DDRAM	
											data.	
Function Set	0	0	0	0	1	DL	N	F	-	-	Set interface data length (DL:	39us
											8-bit/4-bit), numbers of display	
											line	
											(N: 2-line/1-line) and, display	
											font type (F: 5x11dots/5x8dots)	
Set CGRAM	0	0	0	1	AC	AC	AC	AC	AC	AC	Set CGRAM address in address	39us
Address					5	4	3	2	1	0	Counter.	
Set DDRAM	0	0	1	AC	AC	AC	AC	AC	AC	AC	Set DDRAM address in address	39us
Address		_	D.E.	6	5	4	3	2	1	0	Counter.	0
Read Busy	0	1	BF	AC	AC 5	AC	AC	AC 2	AC	AC	Whether during internal	0us
Flag and				6	3	4	3	2	1	0	operation or not can be known by reading	
Address											BF.	
											The contents of address counter	
											can also be read.	
Write Data to	1	0	D7	D6	D5	D4	D3	D2	D1	D0	Write data into internal RAM	43us
RAM								-			(DDRAM/CGRAM).	
Read Data	1	1	D7	D6	D5	D4	D3	D2	D1	D0	Read data from internal RAM	43us
from RAM											(DDRAM/CGRAM).	

*"-": don't care

5-3 EXAPLES OF DATA TRANSFER OPERATION

5-3-1 8 BIT MODE

Power on



	Function set (39µs)												
RS R/W DB7 DB6 DB5 DB4 DB3 DB2 DB1 DB													
0	0	0	0	1	1	N	F	X	X				

N: 0, 1-line mode; 1, 2-line mode.

F: 0, display off; 1, display on.

	Display ON/OFF Control (39µs)												
RS R/W DB7 DB6 DB5 DB4 DB3 DB2 DB1 DB0													
0	0	0	0	0	0	1	D	С	В				

D: 0, display off; 1, display on

C: 0, cursor off; 1 cursor on

B: 0, blink off; 1, blank on

Display Clear (39µs)										
RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	
0	0	0	0	0	0	0	0	0	1	

	₩											
	Entry Mode Set (1.53ms)											
RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0			
0	0	0	0	0	0	0	1	I/D	SH			

I/D: 0, decrement mode; 1, increment mode.

SH: 0, entire shift off; 1, entire shift on.

Initialization end

5-3-2 4 BIT MODE

Power on

Wait for more than 30 ms after VDD riase to 4.5 V



	Function set (39µs)										
RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		
0	0	0	0	1	0	X	X	X	X		
0	0	0	0	1	0	X	X	X	X		
0	0	N	F	X	X	X	X	X	X		

N: 0, 1-line mode; 1, 2-line mode.

F: 0, display off; 1, display on.

	Display ON/OFF Control (39µs)										
RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		
0	0	0	0	0	0	X	X	X	X		
0	0	1	D	С	В	X	X	X	X		

D: 0, display off; 1, display on

C: 0, cursor off; 1 cursor on

B: 0, blink off; 1, blank on

	Display Clear (39µs)										
RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		
0	0	0	0	0	0	X	X	X	X		
0	0	0	0	0	1	X	X	X	X		



	Entry Mode Set (1.53ms)										
RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		
0	0	0	0	0	0	X	X	X	X		
0	0	0	1	I/D	SH	X	X	X	X		

I/D: 0, decrement mode; 1, increment mode.

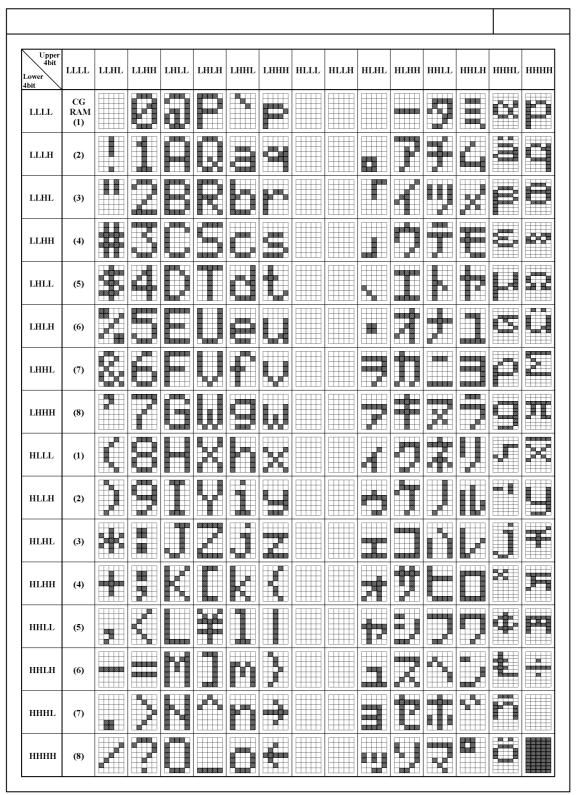
SH: 0, entire shift off; 1, entire shift on.

Initialization end

6. CHARACTER FONT TABLE

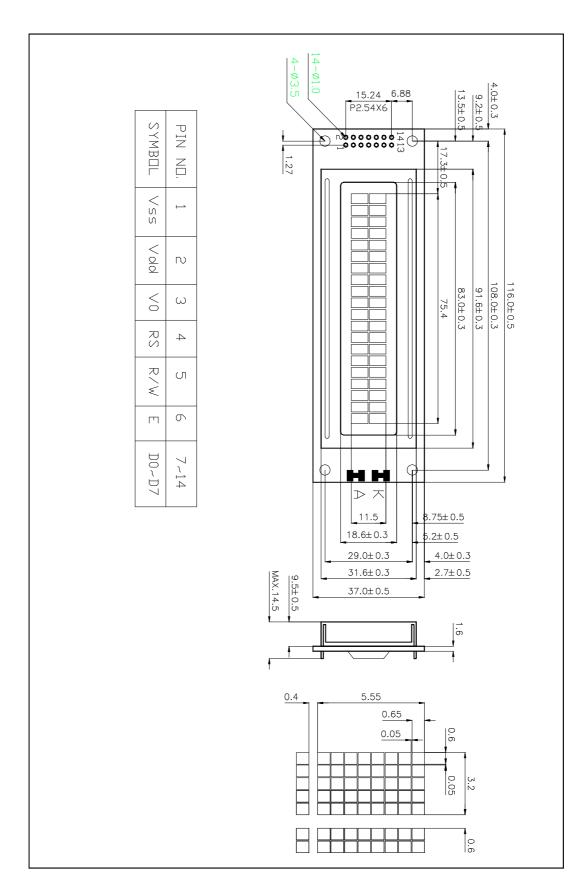
[CORRESPONDENCE BETWEEN CHARACTER CODE AND CHARACTER PATTERN]

Standard Character Pattern



Thu Jun 05 08:41:48 1997

7. DIMENSIONAL OUTLINE



8.QUALITY SPECIFICATION

8-1.ACCEPTABLE QUALITY LEVEL

Inspection items	Sampling procedures	AQL
Visual-operating (Electro-optical)	MIL-STD-105D Inspection level ? Normal inspection Single sample inspection	1.5
Visual-not operating	MIL-STD-105D Inspection level? Normal inspection Single sample inspection	1.5
Dimension measurement	MIL-STD-105D Inspection level ? Normal inspection Single sample inspection	1.0

8-2. INSPECTION CONDITIONS

8-2-1. THE ENVIRONMENTAL

-Room temperature: 25±3 °C -Humidity: 65±20% RH

8-3. INSPECTION STANDARDS

8-3-1. VISUAL WHILE OPERATING

Items to be inspected	Inspection standard
. No display	. If any pattern is not active at all, they can be rejected.
. Irregular operating	. No irregular operating are allowed. Appeared different display, which they should be chosen in the pattern, or appeared in different position where they should be chosen.
.Irregular display	. Any segment doesn't active, they can be rejected.
. Over current	. The total current required to activate the module should not be exceed the MAX current in specification.
.View angles	. Valves that don't meet the minimum value noted in the specification. they can be rejected.
.Contrast	. Valves that don't meet the minimum value noted in the specification, they can be reject.
.LCD operate voltage	. Meet the specification.

HEBEI GEM-TECH ELECTRONICS CO., LTD. 17

8-3-2. Visual while not operating

Module dimension	. Meet the module outline drawing, not exceed the tolerance.
LCD panel scratch	.Following scratches inside the effective viewing area considered as the
	defects when their width & length are larger than the following
	combinations.
	Number: one or more Width: 0.15 length: 5.0
	two or more Width: 0.10 length: 3.0
	three or more Width: 0.05 length: 2.0
	When the defects exceed this, it can be rejected.

9.RELIABILITY

Standard Specification for Reliability of General-purpose LCM

Test Item	Test Condition	Note
High Temperature Store	60 °C,200hr.	2
Low Temperature Store	-10 °C,200hr	2
Humidity Store	60 °C,90% RH,96hr	1,2
High Temperature Operation	40 °C,typical operating conditions,200hr	
Temperature	-10 °C~25 °C~60 °C~25 °C	1,2
Cycling	10 min. between each step temp	
	50 min. at each step. 5 cycles	
Mechanical	10~55Hz sweep, 3G, ampl.=10mm(max) XYZ	
Vibration	for 10 min, each.	

Note 1: Condensation of water is not permitted on the module.

Note 2: The module should be inspected after 1 hour storage in normal conditions (15~35 °C,45~65%RH)

10. HANDLING PRECAUTION

10-1. MOUNTING METHOD

The panel of the LCD module consists of two thin glass plates with polarizes which easily get damaged since the module is fixed by utilizing fitting holes in the printed circuit board. Extreme care should be taken when handling the LCD modules.

10-2. CAUTION OF LCD HANDLING & CLEANING

When cleaning the display surface. Use soft cloth with solvent (recommended below) and wipe lightly.

- -Isopropyl alcohol
- -Ethyl alcohol
- -Tri chlorotri fluoroethane

Do not wipe the display surface with dry or hard materials that will damage the polarizes surface.

Do not use the following solvent:

- -Water
- -Ketone
- -Aromatics

HEBEI GEM-TECH ELECTRONICS CO., LTD. 18 P/N: GTC-20021YR6N0C

10-3.CAUTION AGAINST STATIC CHARGE

The LCD modules use COMS LSI drivers. So we recommend that you connect any unused input terminal to Vdd or Vss, do not input any signals before power is turned on and ground your body. work/assembly table. And assembly equipment to protect against static electricity.

10-4.PACKAGING

- -Modules use LCD elements, and must be treated as such avoid intense shock and falls from a height
- -To prevent modules from degradation, do not operate or store them exposed directly to sunshine or high temperature/humidity.

10-5.CAUTION FOR OPERATION

- -It is indispensable to drive LCM within the specified voltage limit since the higher voltage than the limit shortens LCM life.
- -Response time will be extremely delayed at lower temperature than the operating temperature range and on the other hand at higher temperature LCD show dark color in them.

However those phenomena do not mean malfunction or out of order with LCD, which will come back in the specified operating temperature range.

- -If the display area is pushed hard during operation. Some font will be abnormally displayed but it resumes normal condition after turning off once.
- -A slight dew depositing on terminals is a cause for Electro-chemical reaction resulting in terminal open circuit.

Under the maximum operating temperature, 50%RH or less is required

10-6 STORAGE

In the case of storing for a long period of time (for instance, for years) for the purpose or replacement use. the following ways are recommended

- -Storage in a polyethylene bag with the opening sealed so as not to enter fresh air outside in it, and with no desiccant.
- -Placing in a dark place where neither exposure to direct sunlight nor light is, keeping temperature in the specified storage temperature range.
 - -Storing with no touch on polarizes surface by the anythingelse.
- (it is recommended to store them as they have been contained in the inner container at the time of delivery from us.

10-7.SAFETY

- -It is recommendable to crash damaged or unnecessary LCD into pieces and wash off liquid crystal by using solvents such as acetone and ethanol, which should be burned up later
- -When any liquid crystal leaked out of a damaged glass cell comes in contact with your hands, please wash it off well with soap and water.

11.PRECAUTION FOR USE

11-1.A limit sample should be provided by the both parties on an occasion when the both parties agree its necessity.

Judgement by a limit sample shall take effect after the limit sample has been established

HEBEI GEM-TECH ELECTRONICS CO., LTD. 19 P/N: GTC-20021YR6N0C and confirmed by the both parties.

- 11-2.On the following occasions, the handling of problem should be decided through discussion and agreement between representative of the both parties
 - -When a question is arisen in this specification.
 - -When a new problem is arisen which is not specified in this specifications.
- -When an inspection specification change or operating condition change in customer is reported to GEM-TECH, and some problem is arisen in this specification due to the change.
- -When a new problem is arisen at the customer's operating set for sample evaluation in the customer size.

HEBEI GEM-TECH ELECTRONICS CO., LTD. 20 P/N: GTC-20021YR6N0C